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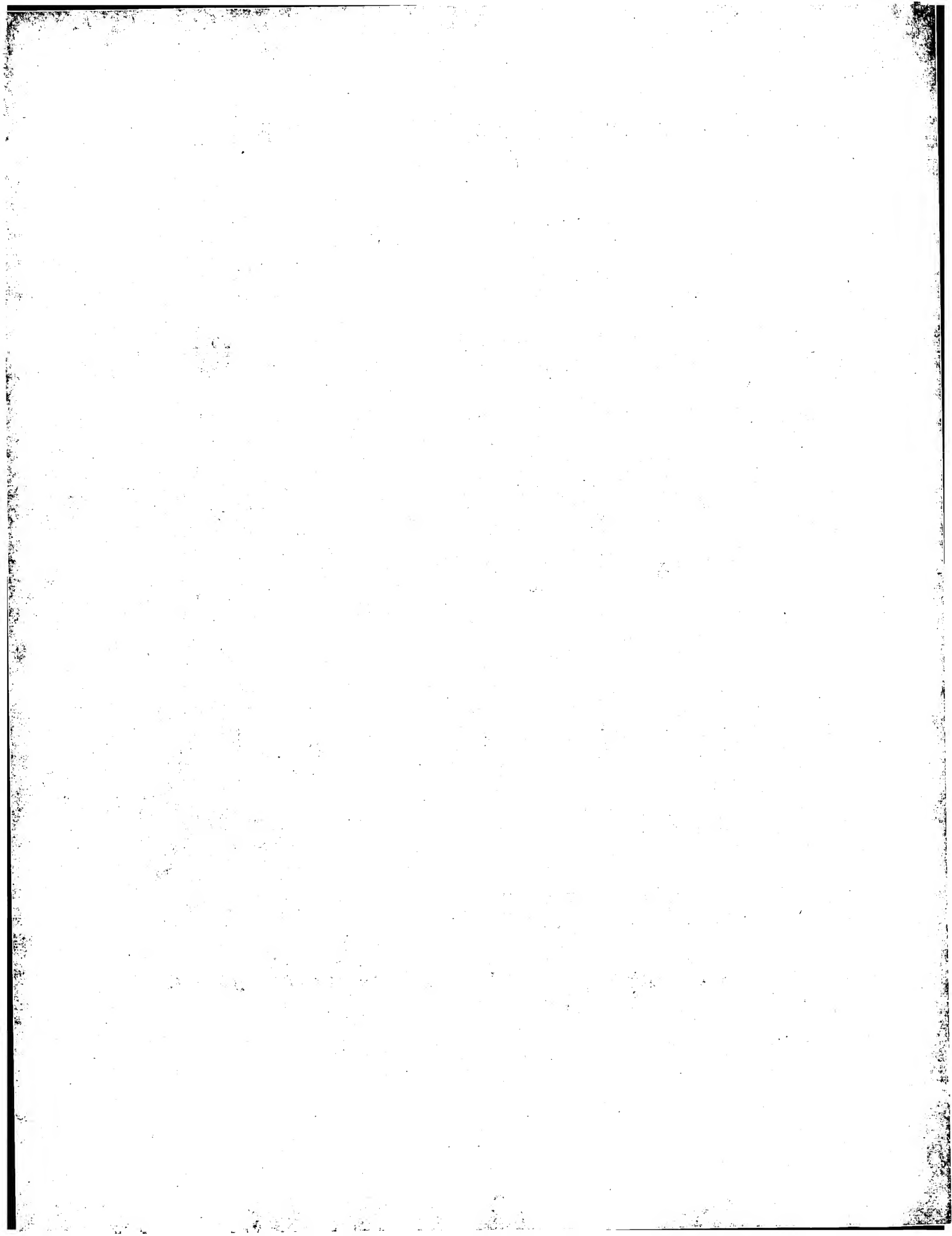
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Patentanmeldung Nr. Patent application No. Demande de brevet n°

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Der Präsident des Europäischen Patentamts;
Im Auftrag

For the President of the European Patent Office

Le Président de l'Office européen des brevets
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Bezeichnung der Erfindung/Title of the invention/Titre de l'invention:
(Falls die Bezeichnung der Erfindung nicht angegeben ist, siehe Beschreibung.
If no title is shown please refer to the description.
Si aucun titre n'est indiqué se referer à la description.)

Radiation pretreated stimuable phosphor screen or panel

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[DESCRIPTION]

FIELD OF THE INVENTION

5 The present invention relates to a stimuable or storage phosphor screen or panel having increased speed or sensitivity.

BACKGROUND OF THE INVENTION

10

When manufacturing stimuable (storage) phosphor plates for digital imaging, all parameters are controlled with the highest care possible, as images should be obtained with the best information possible, i.e. an optimized signal to noise ratio. One of the most
15 important factors related with that signal to noise ratio is speed (sensitivity) of the storage phosphors in the storage phosphor plate or panel.

A higher speed stands for detection of higher amounts of
20 photons by the photomultiplier. Noise is directly related with the number of detected quanta and is proportional therewith.

Speed of a plate or panel for computed radiography, also called CR, is determined by the number of emitted photons per dose unit, set free by photostimulation of energy, stored in the stimuable
25 phosphors after exposure to X-rays.

Improving speed for X-rays of imaging plates by heat treatment has already been described before in literature: such a treatment, e.g. by heating during 4 hours at 170°C, requires quite a lot of
30 time and such an application demands presence of heat resistant substrates as it should withstand at least such high temperatures of 170°C, set forth.

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OBJECTS AND SUMMARY OF THE INVENTION

As production is time consuming it is an ever lasting demand to
5 provide efficient measures, less time consuming and destructive than
e.g. heat treatment procedures in order to increase speed for
storage phosphor panels in computed radiography.

It is therefor an object of the present invention to insure
10 production of storage phosphor plates or panels providing an
optimized signal to noise relationship in the images obtained when
digitally processing said plates after X-ray exposure.

The above-mentioned advantageous effects have been realised by
15 the specific features set out in claim 1.

Specific features for preferred embodiments of the invention
are set out in the dependent claims.

20 Further advantages and embodiments of the present invention
will become apparent from the following description [and drawings].

BRIEF DESCRIPTION OF THE DRAWINGS

25 Fig. 1A shows 4 regions of a screen or panel, coated with a
phosphor, pretreated before exposure in order to get a
UV-luminescence signal: from left to right the regions were
not pre-exposed;
30 pretreated with radiation energy having a wavelength of 254 nm;
pretreated with radiation energy having a wavelength of 365 nm;
pretreated with radiation energy having wavelengths of 254 nm and
365 nm.

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FIG. 1B shows the corresponding sensitivity profile of the different regions of the storage phosphor panel (further explained in the examples hereinafter).

5 Fig. 2A is illustrative for the inscription or marking ability with a UV-laser (266 nm) of storage phosphor panels when not pre-exposed to radiation having a wavelength of 254 nm. The phosphor plate can be marked with an ultraviolet laser, e.g. at 266 nm, even without pre-exposure, but the effect described herein is not
10 detectable on those sites that have been exposed to radiation at 254 nm anymore, as those sites are saturated.

 Fig. 2B is illustrative for the inscription or marking ability with a UV-laser (e.g. 266 nm) of storage phosphor panels when pre-
15 exposed to radiation having a wavelength of 254 nm: due to a "saturation effect" the visibility at 254 nm is decreased.

DETAILED DESCRIPTION OF THE INVENTION

20

 It has surprisingly been established that the sensitivity of stimuable phosphors for X-rays is remarkably improved when an optical pretreatment is applied to the stimuable phosphor plate or panel: pretreatment at short ultraviolet wavelengths, preferably
25 applied in the wavelength range from 150 nm up to 300 nm as e.g. by means of mercury vapour lamp emission at 254 nm, during a few seconds only, at a high intensity, offers a valuable tool to the manufacturer in order to reach the objects of the present invention set forth hereinbefore.

30

 According to the present invention a storage phosphor screen or panel thus provides ratios of ultraviolet luminescence intensities of at least 10/9 after having been exposed to radiation having a wavelength in the range from 150 to 400 nm, measured at same sites
35 of the screen or panel, once without and once with pretreatment of said storage phosphor screen or panel with short-ultraviolet

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radiation in the range from 150 to 300 nm, with an energy of at least 10 mJ/mm^2 . In a more preferred embodiment according to the present invention a storage phosphor screen or panel is provided wherein said ratio is at least 10/7, and even more preferred, 5 wherein said ratio is at least 10/5.

Apart from an ultraviolet radiation source use is advantageously made from ultraviolet lasers. Examples of said ultraviolet lasers are a quadruplicated Nd:YAG laser at 266 nm - 10 thereby making use of the fourth harmonic of said laser, normally exciting at 1064 nm - quadruplicated Nd:YLF and Nd:YVO lasers. Nd:YLF lasers, made available by QUANTRONIX Corporation 41 Research Way East Setauket NY 11733, USA, are even suitable for use at differing wavelengths, namely at 209, 211, 262 and 263 nm. In the 15 alternative an Alexandrite laser emitting at 193 nm, produced by LIGHT AGE, Inc., Two Riverview Drive Somerset, NJ 08873, USA, is advantageously used.

Even more surprising is presence of a lower ultraviolet 20 luminescence signal, after application of such an optical or radiation pretreatment. If a lower ultraviolet luminescence signal is detected after such a pretreatment with ultraviolet radiation in the short UV range (200 nm to 300 nm), an effective increase of speed or sensitivity of the storage phosphor plate is effectively 25 attained.

UV luminescence (at 254 and 365 nm, after irradiation with 254 nm) on the contrary thus shows a decreasing efficiency, even up to 50 %! A ratio of up to 2:1 (10/5) for the ultraviolet luminescence 30 signals, respectively before and after short UV-pretreatment, is thus measured, wherein irradiation pretreatment of the storage phosphor plate proceeds with radiation having a wavelength of e.g. 254 nm (as in case of a mercury lamp) or 266 nm (as in case of a UV-laser).

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According to the present invention optical exposure pretreatment in order to increase sensitivity or speed of storage phosphor panels has been realised by irradiation with radiation sources selected from the group consisting of a mercury vapour lamp (at 254 nm), a deuterium lamp, a xenon lamp and a krypton lamp (both providing selected emission lines in the desired short ultraviolet range between 200 nm and 300 nm), a quadruplicated Nd:YAg laser at 266 nm - making use of the fourth harmonic oscillation -, dye lasers having an ultraviolet emitting dye (such as e.g. BMT - benzene-methanethiol - and PTP - p-Terphenyl $C_{18}H_{14}$), excimer lasers (e.g. those with a gas as F_2 , ArF (193 nm), KrF (248 nm), XeBr (282 nm) or XeCl (308 nm), and frequency-enhanced (doubled- or quadruplicated) diode lasers.

According to the present invention it is not excluded to combine this ultraviolet irradiation pretreatment with the formerly known heat treatment: combination of both pretreatment techniques further combines the advantages offered by both.

According to the present invention an ultraviolet pretreatment is applied in the manufacturing process during or after one or more steps as e.g. during or after vapourisation of the raw stock materials (wherein the ultraviolet radiation source is mounted in the vapourisation apparatus), during the step between vapourisation and heat treatment, during heat treatment (providing presence of the ultraviolet source in the oven wherein heating proceeds).

Following advantageous effects, apart from speed increase, are obtained by the short ultraviolet treatment set forth hereinbefore, thereby providing particularly suitable applications.

According to the present invention the exposure pretreatment method is applicable to storage phosphor plates, showing lack for homogeneity in speed (sensitivity) over the surface of the plate or panel. When varying the intensity of the short-UV-pretreatment as a function of speed differences over the said surface (e.g. by means

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of a compensating filter equalising differences as measured before), speed is not only increased, but homogeneity is improved and even corrected in order to have an excellent speed level and equal speed distribution over the whole panel surface. So sites showing an inferior speed are "corrected in speed" by a higher short-UV pretreatment dose than sites showing a higher speed.

According to the present invention a method is thus offered of producing a stimuable phosphor screen or panel having homogeneous speed distribution over its surface by radiation exposure treatment with energy from a radiation source emitting short ultraviolet radiation in the range from 150 to 300 nm to the said storage phosphor plate or panel originally having inhomogeneous speed distribution over its panel surface by the step of compensating deviations from speed homogeneity point by point by scanning the panel with said radiation source by the step of emitting variable energy amounts in order to compensate for the said deviations.

Further according to the present invention a method of producing a stimuable phosphor screen or panel is offered, said screen or panel having homogeneous speed distribution over its surface by radiation exposure treatment with energy from a radiation source emitting short ultraviolet radiation in the range from 150 to 300 nm to the said storage phosphor plate or panel, originally having inhomogeneous speed distribution over its panel surface by the step of compensating deviations from speed homogeneity by integrally irradiating the screen or panel, after covering it partially with one or more filters having differing densities, thus partially absorbing radiation source emitting short ultraviolet radiation in the range from 150 to 300 nm at differing parts.

A method is further offered, providing inscription of markings with a short-UV-laser in the storage phosphor screen or panel in order to make identification possible: differences obtained in ultraviolet luminescence afterwards when the panel is exposed to

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ultraviolet radiation, preferably having a longer wavelength. Also a reading out procedure with the same wavelength still provides acceptable results, although, when proceeding marking on the complete surface, a text becomes less clearly visible, so that in practice a longer wavelength is preferable. Visibility of such markings due to differences in ultraviolet luminescence thus provide opportunities for practical applications. Apart for the modern, flexible and programmable identification mark or inscription by means of laser having a wavelength in the range from 150 to 300, reason why use of a laser is preferrable and recommended, it is not excluded to provide markings by means of a mercury vapour lamp or similar means, and also by means of a mask. The markings will have a lower density as luminescence decreases and, as the marked sites have a higher speed when exposed to X-rays, it is clear that the marked sites will moreover be visible in the image obtained after digitally processing the screen or panel.

Thus according to the present invention a method is offered of providing a storage phosphor panel with an identification mark or inscription by means of laser, mercury vapour lamp or a mask, wherein marking proceeds with a laser having a wavelength in the range from 150 to 300 nm. According to the method of the present invention said identification mark or inscription is a readable text (with figures and characters) or a machine readable code, and further according to the method of the present invention said identification mark or inscription is a bar code.

According to the present invention a storage phosphor screen or panel comprises a phosphor, wherein said phosphor is an alkali metal halide phosphor. In a more preferred embodiment according to the present invention in said storage phosphor screen or panel, said phosphor is a CsX:Eu stimuable phosphor, wherein X represents a halide selected from the group consisting of Br and Cl, prepared by a method comprising the steps of :

- mixing said CsX with between 10^{-3} and 5 mol % of an Europium

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compound selected from the group consisting of EuX'_2 , EuX'_3 and EuOX' , X' being a member selected from the group consisting of F, Cl, Br and I,

- firing said mixture at a temperature above 450 °C
- 5 - cooling said mixture and
- recovering the CsX:Eu phosphor.

Still more preferred according to the present invention is a binderless storage phosphor screen, containing a CsX:Eu stimuable
10 phosphor, wherein X represents a halide selected from the group consisting of Br and Cl, and wherein said screen is prepared by a method comprising the steps of :

- mixing said CsX with between 10^{-3} and 5 mol % of an Europium compound selected from the group consisting of EuX'_2 , EuX'_3 and
15 EuOX' , X' being a halide selected from the group consisting of F, Cl, Br and I;
- bringing said mixture in condition for vapour deposition and
- depositing said mixture on a substrate by a method selected from the group consisting of physical vapour deposition, thermal vapour
20 deposition,, chemical vapour deposition, electron beam deposition, radio frequency deposition and pulsed laser deposition.

In another embodiment according to the present invention a storage phosphor screen is provided, wherein said phosphor is a
25 CsX:Eu stimuable phosphor, wherein X represents a halide selected from the group consisting of Br and Cl, wherein said screen is prepared by a method comprising the steps of mixing said CsX with between 10^{-3} and 5 mol % of a Europium compound selected from the group consisting of EuX'_2 , EuX'_3 and EuOX' , X' being a halide
30 selected from the group consisting of F, Cl, Br and I; firing said mixture at a temperature above 450 °C; cooling said mixture and recovering the CsX:Eu phosphor; followed by making a lacquer, based on said phosphor, on one or more polymer binders and one or more solvents; coating said lacquer on a substrate and drying a coated
35 layer in order to provide a coated CsX:Eu phosphor layer.

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According the present invention a method is offered of producing a stimuable phosphor screen or panel characterised in that during or after at least one of the manufacturing steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm with an energy of at least 10 mJ/mm^2 .

Further a method for producing a binderless storage phosphor screen according to the present invention is offered, said method comprising the steps of :

- providing an alkali metal halide storage phosphor
- vacuum depositing said phosphor on a substrate characterised in that during said vacuum depositing step said substrate is kept at a temperature T, such that $50^\circ\text{C} \leq T \leq 300^\circ\text{C}$ and that said vacuum deposition proceeds in an Ar-atmosphere with an Ar-pressure of at most 3 Pa, characterised in that during or after at least one of the said steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm.

20

Moreover in a further preferred embodiment a method for producing a binderless storage phosphor screen is offered, said method comprising the steps of :

- combining phosphor precursors for an alkali metal halide storage phosphor,
- vacuum depositing said combination of phosphor precursors on a substrate characterised in that during said vacuum depositing step said substrate is kept at a temperature T, such that $50^\circ\text{C} \leq T \leq 300^\circ\text{C}$ and said vacuum deposition proceeds in an Ar-atmosphere with an Ar-pressure of at most 3 Pa, characterised in that during or after at least one of the said steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm.

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According to the present invention a method for producing a binderless CsX:Eu phosphor screen is further offered, wherein X represents a halide selected from the group consisting of Br and Cl, comprising the steps of :

- 5 - mixing or combining CsX with between 10^{-3} mol % and 5 mol % of a europium compound,
- vapour depositing that mixture onto a substrate, forming a binderless phosphor screen,
- cooling said phosphor screen to room temperature,
- 10 - bringing said phosphor screen to a temperature between 80 and 220 °C and
- maintaining it at that temperature for between 10 minutes and 15 hours,

characterised in that during or after at least one of the said
15 steps a radiation exposure pretreatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 to 300 nm.

In the methods according to the present invention as described
20 above, said radiation source is selected from the group consisting of a mercury vapour lamp at 254 nm, a deuterium lamp, a xenon lamp, a krypton lamp, a quadruplicated - frequency enhanced - Nd:YAG, Nd:YLF, a Nd:YVO or an Alexandrite laser, a dye laser, an excimer laser and a frequency-doubled diode laser.

25

More preferably, according to the method of the present invention, said radiation source is selected from the group of gas excimer lasers consisting of F₂ (157 nm), ArF (193 nm), KrF (248
nm), XeBr (282 nm) and XeCl (308 nm).

30

Identification is another important application with respect to controll of the production as a function of the raw stock materials used during manufacturing of the storage phosphor screens or panels.

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While the present invention will hereinafter be described in connection with preferred embodiments as in the examples thereof, it will be understood that it is not intended to limit the invention to those embodiments.

5

EXAMPLES

Preparation of the phosphor screens.

10 CsBr:Eu screens were made via thermal vapour deposition of CsBr and EuOBr. Therefor CsBr was mixed with EuOBr and placed in a container in a vacuum deposition chamber. The phosphor was deposited on a glass disk with a thickness of 1.5 mm and a diameter of 40 mm. The distance between the container and the substrate was 10 cm. During
15 evaporation, the substrate was rotated at 12 r.p.m.. The container with starting materials was heated to a temperature of 750°C. Before the start of the evaporation, the chamber was evacuated to a pressure of $4 \cdot 10^{-5}$ mbar. During the evaporation process, Ar was introduced in the chamber at a pressure between 1.0
20 and 2.5 Pa, whereas the substrate was heated up to a temperature of 150°C. The Eu-concentration in the evaporated screen was measured with X-ray fluorescence and was of the order of 800 ppm. Scanning Electron Microscopy (SEM) provided information about the morphology of the deposited phosphor layer: the phosphor layer was
25 made up of needle shaped crystals.

Controlling under UV radiation (having a wavelength of 254 nm or 365 nm, as the experiments have been performed with the 254 nm line and the 365 nm line of a mercury vapour lamp - although
30 radiation from the whole excitation spectrum in the range from 200 to 400 nm is not excluded and provides acceptable results) of the stimulable phosphor screen or panel thus obtained, led to the conclusion that a less intense UV luminescence signal was obtained at sites on the screen or panel, previously exposed to short-UV-rays
35 with a radiation wavelength of 254 nm, obtained by a mercury lamp

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during 2 seconds or with the radiation wavelength of 266 nm obtained by a UV laser in the millisecond time range.

Exposure of the panel to radiation having a wavelength outside
5 the range of 150 to 300 nm however as applied in practice with a radiation source of 365 nm does not show any influence upon UV luminescence.

In another experiment wherein the screen or panel has partially
10 been covered with aluminum strips in order to have 4 differing fields, followed by exposure, one by one, as indicated hereinafter, and further exposed integrally after simultaneous removal of all aluminum strips in order to get UV luminescence, shows a clearly lower luminescence for those parts of the panel which were treated
15 with a radiation energy having a wavelength of 254 nm before.

This effect has been shown in Fig. 1A (showing as differing parts from left to right)

-a field having been exposed afterwards to 254 nm + 365 nm
20 (intermediate density);

-a field having been exposed afterwards to 254 nm (most dark field as showing less UV luminescence);

-a field having been exposed to 365 nm (emitting most UV luminescent radiation and therefor looking the brightest field) and

25 -a "comparison field" (where aluminum strips were not removed and which was thus not exposed to UV as an aftertreatment.

The corresponding sensitivity profiles for the different fields, measured as "SAL" have been illustrated in Fig. 1B. The
30 sensitivities of those different fields or zones on the screen were measured in the following way: the screens were homogeneously exposed with a dose of ca. 50 mR at 80 kVp. Read-out was done in a flying spot scanner. In the scanner, the scanning light source was a 30 mW diode laser emitting at 685 nm. A 3-mm BG-39[®] (trade name of
35 Schott) filter coated at both sides with a dielectrical layer was

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used in order to separate the stimulation light from the screen emission light. The scan-average levels (SAL's) were determined as the average signal produced by the screen fields in the photomultiplier tube.

5

As a result an unambiguous increase of sensitivity has been found for the zone after an exposure treatment to radiation with a wavelength of 254 nm: an increase from about 400 nm (comparison zone) to 540 (zone with highest sensitivity) represents a convincing
10 sensitivity increase of about 35 % !

UV post-treatment has thus advantageously been applied: regions of the sheet or panel showing decreased ultraviolet luminescence after exposure to radiation having a wavelength of 254 nm show a
15 sensitivity which is increased versus the non-exposed areas with about 35 %!

Inscriptions in form of a line with a UV laser having an exposure wavelength of 266 nm laser have been illustrated in Fig.
20 2A.

The patterns thus created have been examined during some time and have been proved to be relatively stable: after 12 hours the pattern is still clearly present, as well as after a heat treatment during 4 hours at 170°C.

25

Fig. 2B shows the X-ray images obtained from the lines having been marked with a UV laser when the storage phosphor plate was pretreated with UV exposure having a wavelength of 254 nm: the storage plate or panel seems to be "saturated" as the laser exposure
30 does not show a real inscription effect. Once saturated a laser inscription has reduced effect. It has been shown unambiguously that with a short-UV-pretreatment X-ray sensitivity or speed is enhanced. Once an increase up to 35 % (which is a very remarkable level) has been attained, saturation effects make that no further
35 inscription is possible, thus putting a bar on it.

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Opposite thereto the surface pretreated with a 365 nm exposure shows the best inscriptions with a UV laser afterwards (see Fig. 2A): the signal is most clearly expressed in the most dark parts where a maximum signal appears, whereas the most brightest parts do
5 not show any signal).

Erasure of the pattern by an erasure procedure as is well-known in the field of storage phosphor plates handling before re-use is not possible. There are indications that a combination of heat
10 treatment and exposure to radiation with a radiation source emitting radiation having a wavelength of 365 nm provides erasure of undesired information. The said heat treatment of the storage phosphor plate or panel is applied in steps, before, during or after irradiation, or a combination thereof, with a radiation source
15 emitting radiation having longer wavelengths (more than 300 nm as e.g. the 365 nm wavelength mentioned hereinbefore).

Having described in detail preferred embodiments of the current invention, it will now be apparent to those skilled in the art that
20 numerous modifications can be made therein without departing from the scope of the invention as defined in the appending claims.

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[CLAIMS]

1. A storage phosphor screen or panel providing ratios of
5 ultraviolet luminescence intensities of at least 10/9 after
having been exposed with radiation having a wavelength in the
range from 150 to 400 nm , measured at same sites of the screen
or panel, once without and once with pretreatment of said storage
phosphor screen or panel with short ultraviolet radiation in the
10 range from 200 nm to 300 nm, having an energy of 10 mJ/mm².
2. Storage phosphor screen or panel according to claim 1, wherein
said ratio is at least 10/7.
3. Storage phosphor screen or panel according to claim 1, wherein
said ratio is at least 10/5.
- 15 4. Storage phosphor screen or panel according to any one of the
claims 1 to 3, wherein said phosphor is an alkali metal halide
phosphor.
5. Storage phosphor screen or panel according to any one of the
claims 1 to 4, wherein said phosphor is a CsX:Eu stimuable
20 phosphor, wherein X represents a halide selected from the group
consisting of Br and Cl, prepared by a method comprising the
steps of :
 - mixing said CsX with between 10⁻³ and 5 mol % of a Europium
compound selected from the group consisting of EuX'₂, EuX'₃ and
25 EuOX', X' being a member selected from the group consisting of F,
Cl, Br and I,
 - firing said mixture at a temperature above 450 °C
 - cooling said mixture and
 - recovering the CsX:Eu phosphor.

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6. A binderless storage phosphor screen according to any one of claims 1 to 4, containing a CsX:Eu stimuable phosphor, wherein X represents a halide selected from the group consisting of Br and Cl, wherein said screen is prepared by a method comprising the steps of :
- mixing said CsX with between 10^{-3} and 5 mol % of a Europium compound selected from the group consisting of EuX'_2 , EuX'_3 and EuOX' , X' being a halide selected from the group consisting of F, Cl, Br and I;
 - bringing said mixture in condition for vapour deposition and
 - depositing said mixture on a substrate by a method selected from the group consisting of physical vapour deposition, thermal vapour deposition,, chemical vapour deposition, electron beam deposition, radio frequency deposition and pulsed laser deposition.
7. Storage phosphor screen according to any one of claims 1 to 4, wherein said phosphor is a CsX:Eu stimuable phosphor, wherein X represents a halide selected from the group consisting of Br and Cl, wherein said screen is prepared by a method comprising the steps of mixing said CsX with between 10^{-3} and 5 mol % of a Europium compound selected from the group consisting of EuX'_2 , EuX'_3 and EuOX' , X' being a halide selected from the group consisting of F, Cl, Br and I; firing said mixture at a temperature above 450 °C; cooling said mixture and recovering the CsX:Eu phosphor; followed by making a lacquer, based on said phosphor, on one or more polymer binders and one or more solvents; coating said lacquer on a substrate and drying a coated layer in order to provide a coated CsX:Eu phosphor layer.
8. Method of producing a stimuable phosphor screen or panel according to any one of the claims 1 to 7, characterised in that during or after at least one of the manufacturing steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm with an energy of at least 10 mJ/mm^2 .

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9. Method for producing a binderless storage phosphor screen according to any one of the claims 1 to 7, said method comprising the steps of :

- providing an alkali metal halide storage phosphor

5 - vacuum depositing said phosphor on a substrate characterised in that during said vacuum depositing step said substrate is kept at a temperature T, such that $50\text{ }^{\circ}\text{C} \leq T \leq 300\text{ }^{\circ}\text{C}$ and that said vacuum deposition proceeds in an Ar-atmosphere with an Ar-pressure of at most 3 Pa, characterised in that during or after
10 at least one of the said steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm with an energy of at least 10 mJ/mm^2 .

10. Method for producing a binderless storage phosphor screen

15 according to any one of the claims 1 to 7, said method comprising the steps of :

- combining phosphor precursors for an alkali metal halide storage phosphor,

20 - vacuum depositing said combination of phosphor precursors on a substrate characterised in that during said vacuum depositing step said substrate is kept at a temperature T, such that $50\text{ }^{\circ}\text{C} \leq T \leq 300\text{ }^{\circ}\text{C}$ and said vacuum deposition proceeds in an Ar-atmosphere with an Ar-pressure of at most 3 Pa, characterised in that during or after at least one of the said steps a radiation
25 exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm with an energy of at least 10 mJ/mm^2 .

11. Method for producing a binderless CsX:Eu phosphor screen,

30 according to any one of the claims 1 to 7, wherein X represents a halide selected from the group consisting of Br and Cl, said method comprising the steps of :

- mixing or combining CsX with between 10^{-3} mol % and 5 mol % of a europium compound,

35 - vapour depositing that mixture onto a substrate, forming a binderless phosphor screen,

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- cooling said phosphor screen to room temperature,
- bringing said phosphor screen to a temperature between 80 and 220 °C and
- maintaining it at that temperature for between 10 minutes and 15 hours, characterised in that during or after at least one of the said steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the range from 150 nm to 300 nm with an energy of at least 10 mJ/mm².

10 12. Method for producing a CsX:Eu stimuable phosphor screen, wherein X represents a halide selected from the group consisting of Br and Cl, wherein said screen is prepared by the method comprising the steps of mixing said CsX with between 10⁻³ and 5 mol % of a Europium compound selected from the group consisting of EuX'₂,
15 EuX'₃ and EuOX', X' being a halide selected from the group consisting of F, Cl, Br and I; firing said mixture at a temperature above 450 °C; cooling said mixture and recovering the CsX:Eu phosphor; followed by making a lacquer, based on said phosphor, on one or more polymer binders and one or more
20 solvents; coating said lacquer on a substrate and drying a coated layer in order to provide a coated CsX:Eu phosphor layer, characterised in that during or after at least one of the said steps a radiation exposure treatment is given with energy from radiation sources emitting short ultraviolet radiation in the
25 range from 150 nm to 300 nm with an energy of at least 10 mJ/mm².

13. Method according to any one of the claims 8 to 12, wherein said radiation source is selected from the group consisting of a mercury vapour lamp at 254 nm, a deuterium lamp, a xenon lamp, a krypton lamp, a quadruplicated - frequency enhanced - Nd:YAG,
30 Nd:YFL, a Nd:YVO or an Alexandrite laser, a dye laser, an excimer laser and a frequency-doubled or quadruplicated diode laser.

14. Method according to claim 13, wherein said radiation source is selected from the group of gas excimer lasers consisting of F₂, ArF, KrF, XeBr and XeCl.

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15. Method of producing a stimuable phosphor screen or panel according to any one of the claims 1 to 7, said screen or panel having homogeneous speed distribution over its surface by radiation exposure treatment with energy from a radiation source emitting short ultraviolet radiation in the range from 150 nm to 300 nm to the said storage phosphor plate or panel originally having inhomogeneous speed distribution over its panel surface, by the step of compensating deviations from speed homogeneity point by point by scanning the panel with said radiation source by the step of emitting variable energy amounts in order to compensate for the said deviations.
16. Method of producing a stimuable phosphor screen or panel according to any one of the claims 1 to 7, wherein said screen or panel has a homogeneous speed distribution over its surface by radiation exposure treatment with energy from a radiation source emitting short ultraviolet radiation in the range from 150 nm to 300 nm to the said storage phosphor plate or panel, originally having inhomogeneous speed distribution over its panel surface by the step of compensating deviations from speed homogeneity by integrally irradiating the screen or panel, after covering it partially with one or more filters having differing densities, thus partially absorbing radiation source emitting short ultraviolet radiation in the range from 150 nm to 300 nm at differing parts.
17. Method of providing a storage phosphor panel according to any one of the claims 1 to 7, with an identification mark or inscription by means of laser, mercury vapour lamp or a mask, wherein marking proceeds with a laser having a wavelength in the range from 150 nm to 300 nm.
18. Method according to claim 17, wherein said identification mark or inscription is a readable text or a machine readable code.
19. Method according to claim 18, wherein said identification mark or inscription is a bar code.

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- 1 -

[ABSTRACT]

TITLE

5 RADIATION PRETREATED STIMULABLE PHOSPHOR SCREEN OR PANEL

A storage phosphor screen or panel has been disclosed, providing ratios of ultraviolet luminescence intensities of at least 10/9 after having been exposed to radiation having a wavelength in
10 the range from 150 to 400 nm , measured at same sites without and with pretreatment exposure of said storage phosphor screen or panel with short ultraviolet radiation in the range from 150 to 300 nm and having an energy of 10 mJ/mm², as well as a method of producing a stimuable phosphor screen or panel, characterised in that during or
15 after at least one of the manufacturing steps a radiation exposure treatment is given with radiation sources emitting short ultraviolet radiation in the range from 150 to 300 nm with an energy of at least 10 mJ/mm².

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FIG. 1A

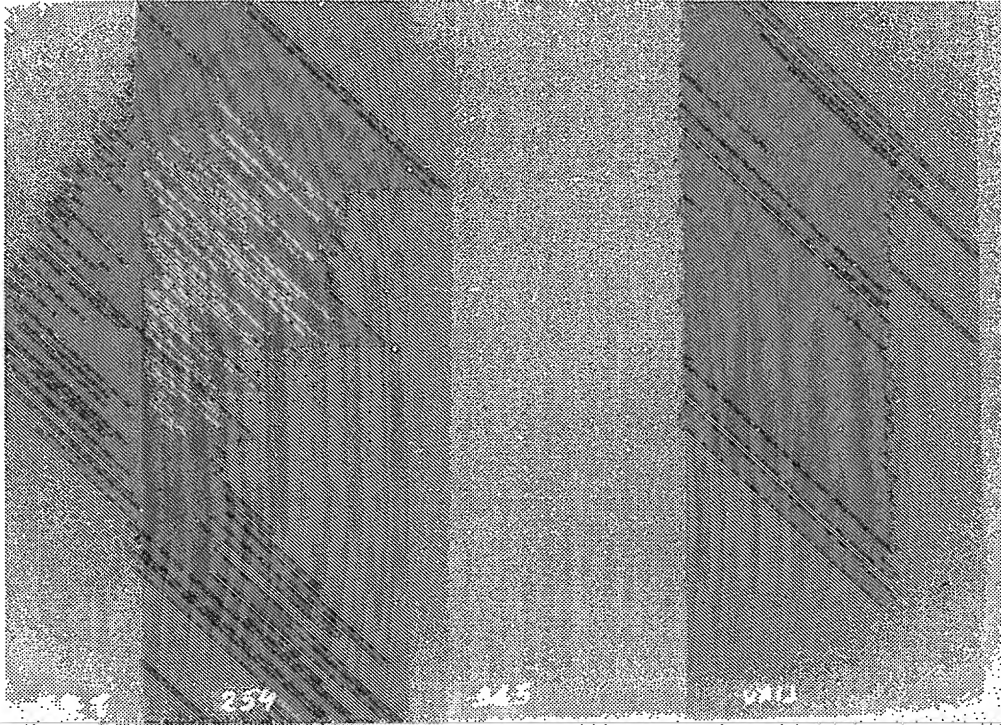
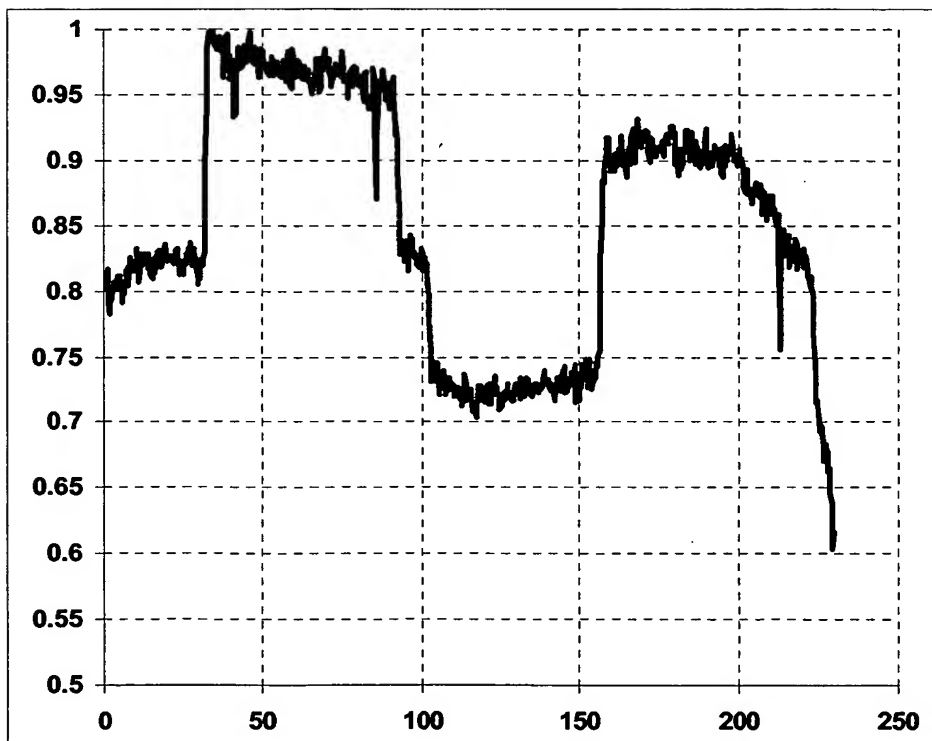


FIG. 1B



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FIG. 2 A

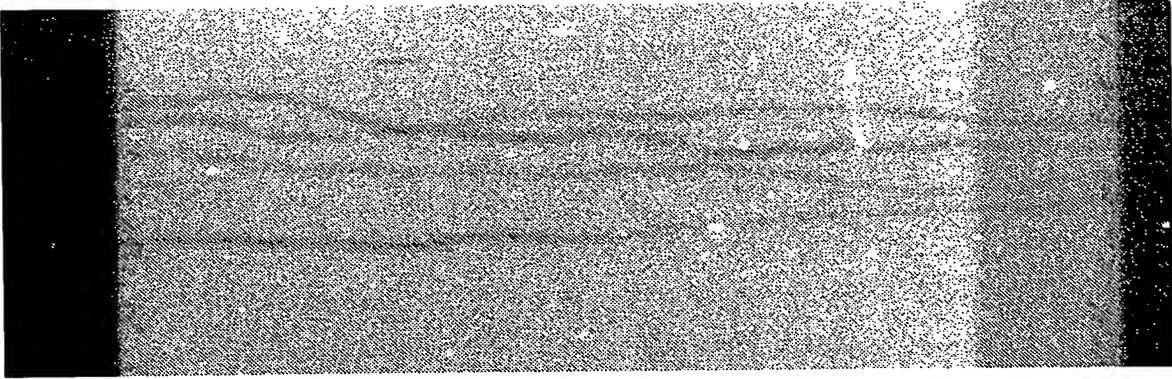
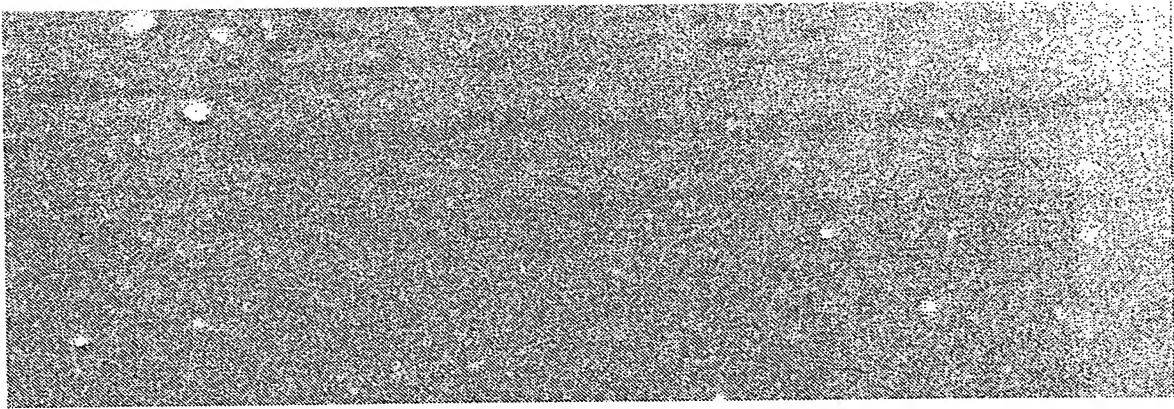


FIG. 2B



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